

**INDUSTRY STANDARD OF THE
PEOPLE'S REPUBLIC OF CHINA**

SJ/T 11824-2022

**Metal Oxide Semiconductor Field Effect Transistor (MOSFET)
Equivalent Capacitance and Voltage Change Rate Test Method**

金属氧化物半导体场效应晶体管（MOSFET）等效电容和电压变化率测试方法
(English Translation)

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What this standard covers

This standard specifies the test methods for the two parameters of metal-oxide semiconductor field effect transistor (MOSFET) equivalent capacitance and voltage change rate.

Document data

Estimated length of the Chinese original: 10,185 words.